# MP5098



## 12V/5V, Low I<sub>Q</sub>, Dual-Channel E-Fuse with Current Monitoring and Low On Resistance

## DESCRIPTION

The MP5098 is a 12V/5V, low quiescent current  $(I_Q)$ , low on resistance  $(R_{DS(ON)})$ , dual-channel efuse protection device with current monitoring. It protects output circuitry from input transients, as well as protects input circuitry from output shorts and transients.

At start-up, the inrush current is limited by limiting the output slew rate. The slew rate is controlled via the SS pin capacitor ( $C_{SS}$ ).

The maximum load current ( $I_{LOAD\_MAX}$ ) at the output is current-limited. The magnitude of the current limit ( $I_{LIMIT}$ ) is fixed internally.

Full protection features include output overvoltage protection (OVP), over-current protection (OCP), short-circuit protection (SCP), and thermal shutdown.

The output voltage ( $V_{OUT}$ ) is limited by output OVP. Each rail's output current ( $I_{OUT}$ ) can be monitored via a resistor connected between the IMON1 and IMON2 pins.

The MP5098 is available in a space-saving TQFN-10 (2mmx3mm) package.

## FEATURES

- 12V/5V Integrated Dual E-Fuse
- Dual-Channel Current Limiting
- 24V/100ms Maximum Surge Input Voltage (V<sub>IN</sub>) Tolerance for 12V Bus and 5V Bus
- 40mΩ Low On Resistance (R<sub>DS(ON)</sub>)
- Low Quiescent Current (I<sub>Q</sub>):
  - $\circ$  210µA I<sub>Q</sub> for 12V Bus
  - $\circ$  190µA I<sub>Q</sub> for 15V Bus
- Configurable Soft-Start Time (tss)
- Fixed Trip/Hold Current Limit (ILIMIT):
  - Fixed 4A Trip ILIMIT for 12V Bus
  - $\circ$   $\;$  Fixed 2.5A Hold I\_LIMIIT for 12V Bus  $\;$
  - Fixed 3A Trip ILIMIT for 5V Bus
  - Fixed 1.3A Hold ILIMIIT for 5V Bus
- 15V Over-Voltage Protection (OVP) Threshold for 12V V<sub>IN</sub> Channel
- 5.7V OVP Threshold for 5V V<sub>IN</sub> Channel
- Over-Current Protection (OCP) with Hiccup Mode
- Short-Circuit Protection (SCP)
- Thermal Shutdown (Latch-Off Protection)
- Available in a TQFN-10 (2mmx3mm) Package

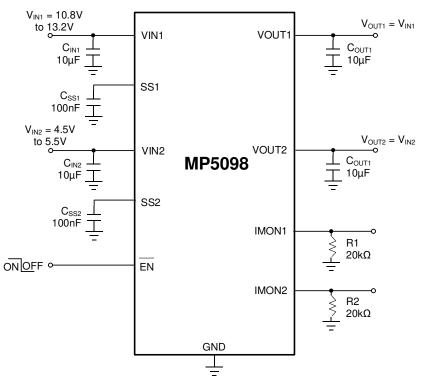
## **APPLICATIONS**

- Hard-Disk Drives (HDDs)
- Solid-State Drives (SSDs)
- Hot Swap Applications

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## **TYPICAL APPLICATION**





### **ORDERING INFORMATION**

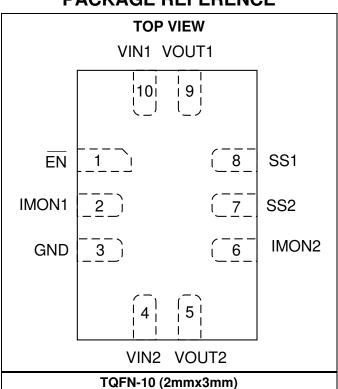
|   | Part Number* | Package           | Top Marking | MSL Rating |
|---|--------------|-------------------|-------------|------------|
| Ī | MP5098GDT    | TQFN-10 (2mm×3mm) | See Below   | 1          |

\* For Tape & Reel, add suffix -Z (e.g. MP5098GDT-Z).

# **TOP MARKING**

| BLB |
|-----|
| YWW |
| LLL |

BLB: Product code of MP5098GDT Y: Year code WW: Week code LLL: Lot number



### PACKAGE REFERENCE



## **PIN FUNCTIONS**

| Pin # | Name  | Description  |
|-------|-------|--|
| 1     | EN    | <b>Channel 1 and channel 2 enable.</b> The $\overline{EN}$ pin is a digital input that turns the regulator on and off. Float $\overline{EN}$ or pull $\overline{EN}$ low to turn the regulator on; pull $\overline{EN}$ high to turn it off. |
| 2     | IMON1 | <b>Channel 1 current monitoring.</b> Connect a resistor between the IMON1 and GND pins to set the current monitor gain.  |
| 3     | GND   | System ground.   |
| 4     | VIN2  | <b>Channel 2 supply voltage.</b> Channel 2's typical input voltage $(V_{IN})$ is 5V. Use a ceramic decoupling capacitor to decouple the VIN2 pin. Connect VIN2 using a wide PCB trace.   |
| 5     | VOUT2 | Channel 2 output terminal.   |
| 6     | IMON2 | <b>Channel 2 current monitoring.</b> Connect a resistor between the IMON2 and GND pins to set the current monitor gain.  |
| 7     | SS2   | <b>Channel 2 soft start.</b> Connect a capacitor between the SS2 and GND pins to set channel 2's soft-start time (tss).  |
| 8     | SS1   | <b>Channel 1 soft start.</b> Connect a capacitor between the SS1 and GND pins to set channel 1's tss.  |
| 9     | VOUT1 | Channel 1 output terminal.   |
| 10    | VIN1  | <b>Channel 1 supply voltage.</b> Channel 2's typical input voltage ( $V_{IN}$ ) is 12V. Use a ceramic decoupling capacitor to decouple the VIN1 pin. Connect VIN1 using a wide PCB trace.  |

## ABSOLUTE MAXIMUM RATINGS (1)

| V <sub>IN1</sub> , V <sub>OUT1</sub> 0.3V to +22V           |
|---|
| Input positive transient (CH1 = 100ms)24V                   |
| V <sub>IN2</sub> , V <sub>OUT2</sub> 0.3V to +15V           |
| Input positive transient (CH2 = 100ms)24V                   |
| All other pins  |
| Junction temperature40°C to +150°C                          |
| Lead temperature  |
| Continuous Power Dissipation $(T_A = 25^{\circ}C)^{(2)(4)}$ |
| TQFN-10 (2mmx3mm)3.1W                                       |

#### ESD Ratings

Human body model (HBM) ......2000V Charged device model (CDM)......1750V

#### **Recommended Operating Conditions** <sup>(3)</sup>

| CH1 continuous voltage                    | 10.8V to 13.8V |
|---|----------------|
| CH2 continuous voltage                    | 4.6V to 5.5V   |
| Operating junction temp (T <sub>J</sub> ) | 40°C to +125°C |

#### 

#### Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature  $T_J$  (MAX), the junction-toambient thermal resistance  $\theta_{JA}$ , and the ambient temperature  $T_A$ . The maximum allowable continuous power dissipation at any ambient temperature is calculated by  $P_D$  (MAX) = ( $T_J$  (MAX) -  $T_A$ ) /  $\theta_{JA}$ . Exceeding the maximum allowable power dissipation can produce an excessive die temperature, which may cause the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on the EV5098-D-00A, 2-layer PCB, 54mmx46mm.
- 5) The value of  $\theta_{JA}$  given in this table is only valid for comparison with other packages and cannot be used for design purposes. These values were calculated in accordance with JESD51-7, and simulated on a specified JEDEC board. They do not represent the performance obtained in an actual application.



# **ELECTRICAL CHARACTERISTICS**

 $V_{IN1}$  = 12V,  $V_{IN2}$  = 5V,  $C_{OUT1}$  =  $C_{OUT2}$  = 10µF,  $T_J$  = -40°C to +125°C  $^{(6)}$ , typical values are tested at  $T_J$  = 25°C, unless otherwise noted.

| Parameter                 | Symbol                      | Condition   | Min  | Тур  | Max  | Units |
|---------------------------|-----------------------------|---|------|------|------|-------|
| Supply Current            |                             |   |      |      |      |       |
| Quiescent current         | I <sub>Q_CH1</sub>          | V <sub>EN</sub> is low  |      | 210  |      | μA    |
|                           | I <sub>Q_CH2</sub>          | V <sub>EN</sub> is low  |      | 190  |      | μA    |
| Chutdown ourront          | I <sub>SD_CH1</sub>         | $V_{EN}$ is high  |      | 15   |      | μA    |
| Shutdown current          | ISD_CH2                     | V <sub>EN</sub> is high   |      | 10   |      | μA    |
| Power MOSFET              |                             |   |      |      |      |       |
|                           | Broken all                  | $T_J = 25^{\circ}C$   |      | 40   | 50   | mΩ    |
| On resistance             | R <sub>DS(ON)</sub> _CH1    | $T_J = 125^{\circ}C$  |      |      | 65   | mΩ    |
| On resistance             | Proven eve                  | $T_J = 25^{\circ}C$   |      | 40   | 50   | mΩ    |
|                           | Rds(on)_ch2                 | $T_J = 125^{\circ}C$  |      |      | 65   | mΩ    |
|                           |                             | From V EN is low to lout1 rises up to   |      |      |      |       |
|                           | ten_delay_ch1               | 100mA, with 1A load resistor, SS1 is floating   |      | 220  |      | μs    |
| Start-up delay            | ten_delay_ch2               | From V EN is low to lout rises up to<br>100mA, with 1A load resistor, SS2 is<br>floating        |      | 220  |      | μs    |
| Under-Voltage Lockout     | (UVLO) Protec               | tion and Over-Voltage Protection (OV  | /P)  | I    |      |       |
|                           | VUVLO_RISING                |   | -    | 10   | 10.4 | V     |
| UVLO rising threshold     | CH1                         |   | 9.6  | 10   | 10.4 | V     |
|                           | VUVLO_ RISING<br>_CH2       |   | 4.25 | 4.35 | 4.45 | V     |
|                           | VUVLO_FALLING_<br>CH1       |   |      | 9.1  |      | V     |
| UVLO falling threshold    | VUVLO_FALLING<br>CH2        |   |      | 2.65 |      | V     |
|                           | VOVP_CH1                    |   | 13.8 | 15   | 16   | V     |
| Output OVP threshold      | V <sub>OVP_CH2</sub>        |   | 5.5  | 5.7  | 5.9  | V     |
| Output OVP response       | tovp_ch1                    | $C_{OUT1} = 10\mu F$ with $30\Omega$ load resistor,<br>V <sub>IN1</sub> = 12V to 18V/10 $\mu$ s |      | 2    |      | μs    |
| time <sup>(7)</sup>       | tovp_ch2                    | $C_{OUT2} = 10\mu F$ with $10\Omega$ load resistor,<br>$V_{IN2} = 5V$ to $7V/10\mu s$           |      | 2    |      | μs    |
| Current Limit (ILIMIIT)   |                             | · · · ·   | •    |      |      |       |
| ILIMIIT during normal     | LIMIT_CH1                   |   | -10% | 4    | +10% | Α     |
| operation                 | ILIMIT_CH2                  |   | -10% | 3    | +10% | Α     |
| Constant-current limit    | ILIMIT_CC_CH1 (7)           |   |      | 2.5  |      | Α     |
| during normal operation   | LIMIT_CC_CH2 <sup>(7)</sup> |   |      | 1.3  |      | Α     |
| ILIMIIT response time (7) | tcL_cH1                     |   |      | 15   |      | μs    |
|                           | tcL_cH₂                     |   |      | 15   |      | μs    |
| Secondary I               | ILIMIT_SEC_CC_<br>CH1       |   |      | 8    |      | А     |
| Secondary ILIMIIT (7)     | ILIMIT_SEC_CC_<br>CH2       |   |      | 8    |      | А     |



## ELECTRICAL CHARACTERISTICS (continued)

 $V_{IN1}$  = 12V,  $V_{IN2}$  = 5V,  $C_{OUT1}$  =  $C_{OUT2}$  = 10µF,  $T_J$  = -40°C to +125°C  $^{(6)}$ , typical values are tested at  $T_J$  = 25°C, unless otherwise noted.

| Parameter  | Symbol          | Condition | Min  | Тур  | Max  | Units |
|--|-----------------|-----------|------|------|------|-------|
| Hiccup mode on time  | ton_HICCUP      |           |      | 2    |      | ms    |
| Hiccup mode off time   | toff_HICCUP     |           |      | 200  |      | ms    |
| <b>Current Monitoring (IMC</b>   | DN1/IMON2)      |           |      |      |      |       |
| Current conce gain   | GIMON1          |           |      | 32   |      | μΑ/Α  |
| Current-sense gain   | GIMON2          |           |      | 34   |      | μΑ/Α  |
| Hiccup mode on time<br>Hiccup mode off time<br><b>Current Monitoring (IMC</b><br>Current-sense gain<br>Current-sense offset<br>Current monitor voltage<br>range <sup>(7)</sup><br><b>Enable (EN) Control</b><br>EN falling threshold<br>EN hysteresis<br>EN pull down<br>resistance<br><b>Soft Start (SS)</b><br>Soft-start current<br><b>Thermal Shutdown</b> | IOFFSET_CH1     |           | 0.45 | 2    | 3.5  | μΑ    |
|  | IOFFSET_CH2     |           | 0.8  | 2.3  | 3.8  | μΑ    |
|  | VIMON           |           | 0    |      | 2.5  | V     |
| Enable (EN) Control  | •               | ·         | ·    |      |      |       |
| EN falling threshold   | Ven_falling     |           | 0.95 | 1.15 | 1.35 | V     |
| EN hysteresis  | Ven_hys         |           |      | 800  |      | mV    |
| EN pull down   | Ren_pd          |           |      | 0.77 |      | MΩ    |
| resistance   |                 |           |      | 0    |      |       |
| Soft Start (SS)  |                 |           |      |      |      |       |
| Coft start surrant   | Iss_CH1         |           | 4    | 5.5  | 7    | μA    |
| Son-start current  | Iss_ch2         |           | 4    | 5.5  | 7    | μA    |
| Thermal Shutdown   |                 |           |      |      |      |       |
| Thermal shutdown (7)   | T <sub>SD</sub> |           |      | 155  |      | °C    |

Notes:

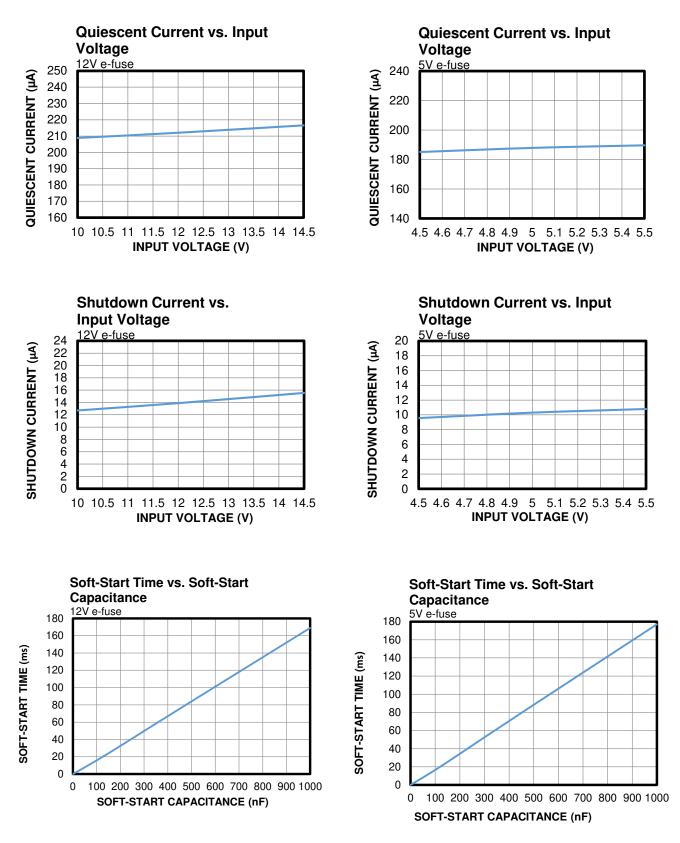
6) Guaranteed by over-temperature correlation. Not tested in production.

7) Guaranteed by engineering sample characterization.



# **TYPICAL CHARACTERISTICS**

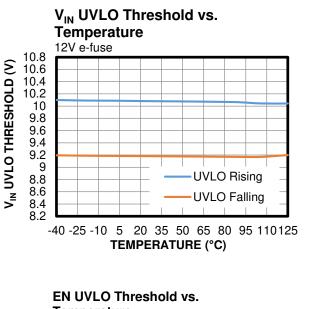
 $V_{IN1} = 12V$ ,  $V_{IN2} = 5V$ ,  $T_A = 25^{\circ}C$ , unless otherwise noted.

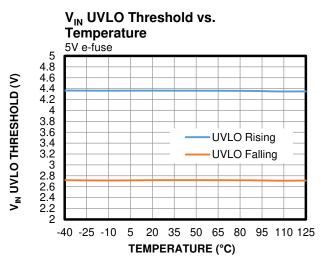




# TYPICAL CHARACTERISTICS (continued)

 $V_{IN1}$  = 12V,  $V_{IN2}$  = 5V,  $T_A$  = 25°C, unless otherwise noted.

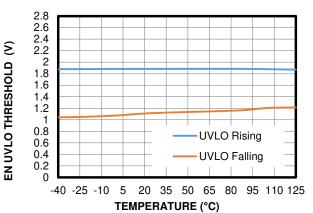


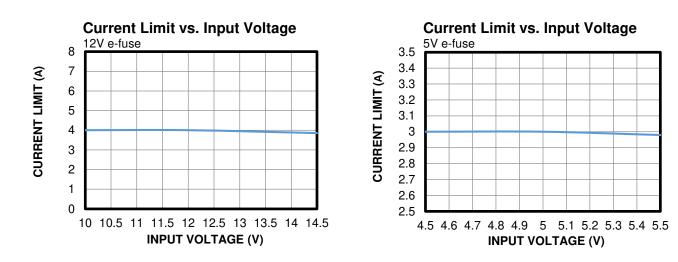


Temperature 12V e-fuse 2.8 2.6 2.4 2.2 EN UVLO THRESHOLD (V) 2 1.8 1.6 1.4 1.2 1 0.8 UVLO Rising 0.6 0.4 **UVLO** Falling 0.2 0 -40 -25 -10 5 20 35 50 65 80 95 110 125

TEMPERATURE (°C)

EN UVLO Threshold vs. Temperature 5V e-fuse

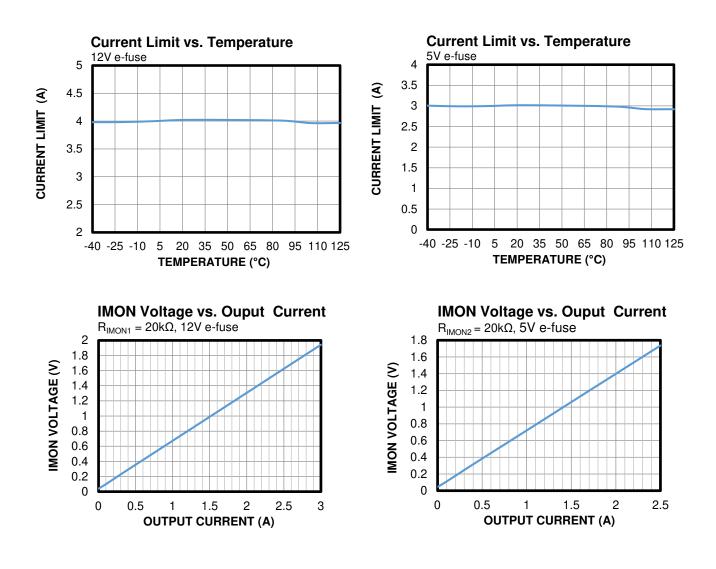






## TYPICAL CHARACTERISTICS (continued)

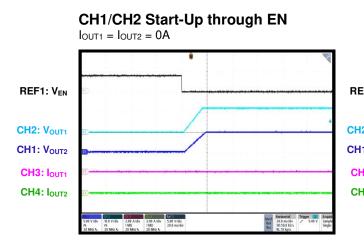
 $V_{IN1}$  = 12V,  $V_{IN2}$  = 5V,  $T_A$  = 25°C, unless otherwise noted.





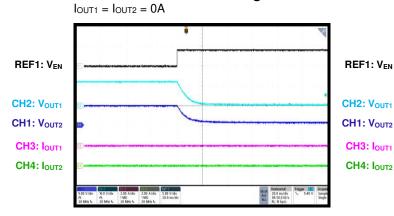
# **TYPICAL PERFORMANCE CHARACTERISTICS**

 $V_{IN1}$  = 12V,  $V_{IN2}$  = 5V,  $T_A$  = 25°C, unless otherwise noted.



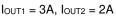
CH1/CH2 Start-Up through EN louT1 = 3A, louT2 = 2A REF1: V<sub>EN</sub> CH2: V<sub>OUT1</sub> CH3: louT1 CH4: louT2

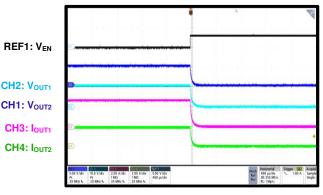
CH1/CH2 Shutdown through EN

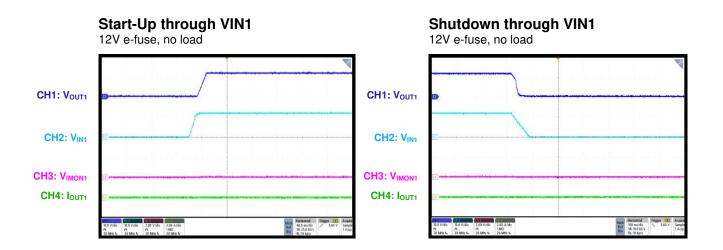


CH1/CH2 Shutdown through EN

5.00 V/v 20.0 ms Math Prinzöntal Trigger 21 Ref 20.0 mc/dv / 5.40 V Bas St. 50.0 k5/s

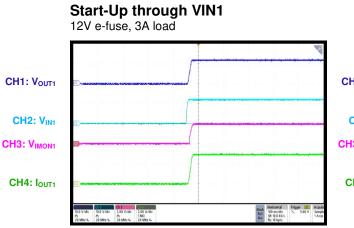


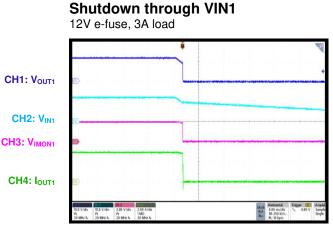




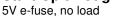


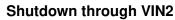
 $V_{IN1}$  = 12V,  $V_{IN2}$  = 5V,  $T_A$  = 25°C, unless otherwise noted.

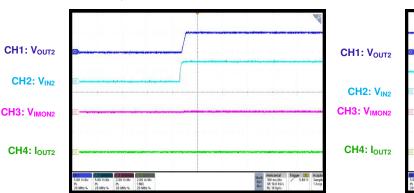




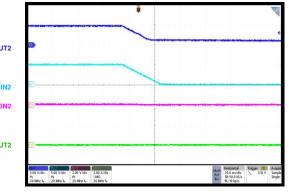
Start-Up through VIN2

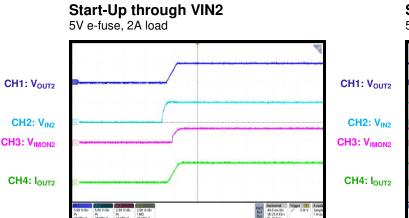




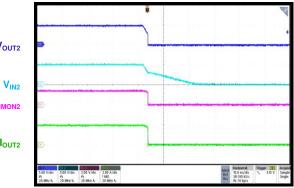


# 5V e-fuse, no load



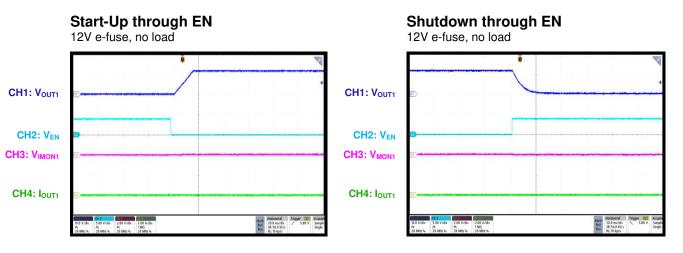


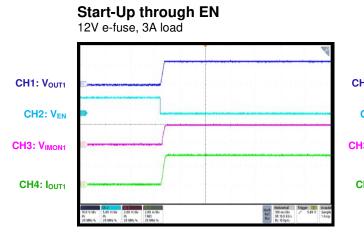
#### Shutdown through VIN2 5V e-fuse, 2A load



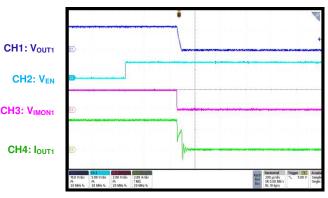


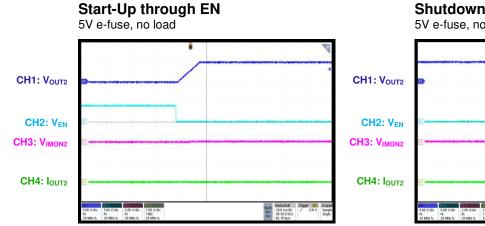
 $V_{\text{IN1}}$  = 12V,  $V_{\text{IN2}}$  = 5V,  $T_{\text{A}}$  = 25°C, unless otherwise noted.



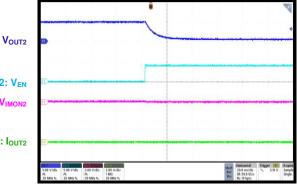


Shutdown through EN 12V e-fuse, 3A load



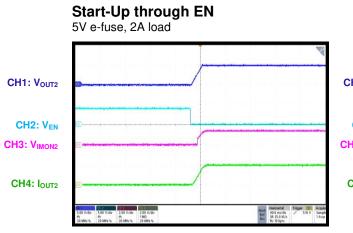


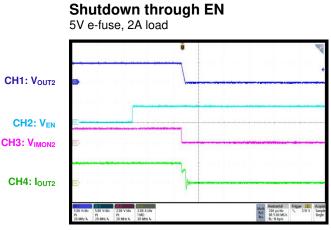
# Shutdown through EN 5V e-fuse, no load





 $V_{\text{IN1}}$  = 12V,  $V_{\text{IN2}}$  = 5V,  $T_{\text{A}}$  = 25°C, unless otherwise noted.





#### Current Limit

CH1: VOUT1

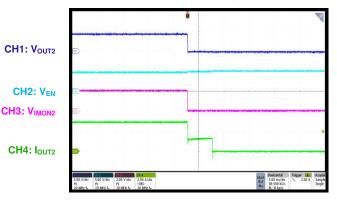
CH2: V<sub>EN</sub> CH3: V<sub>IMON1</sub>

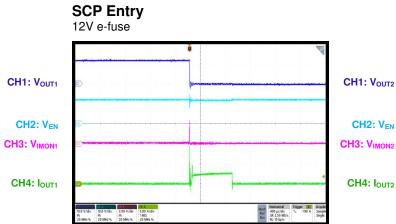
CH4: IOUT1

12V e-fuse, IOUT increases slowly

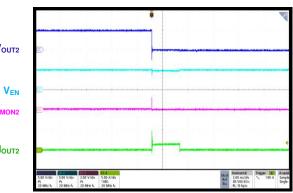
#### Current Limit

5V e-fuse, IOUT increases slowly





#### SCP Entry 5V e-fuse

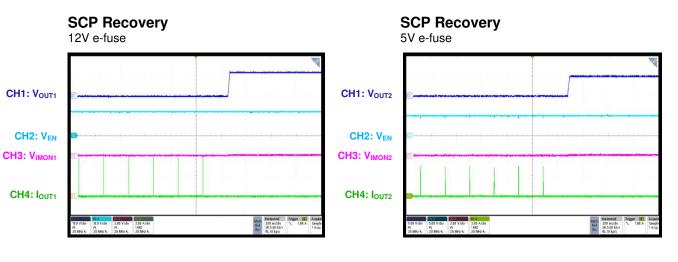


2 04 A

Math Ref 200 µs/div SR:5.00 MS

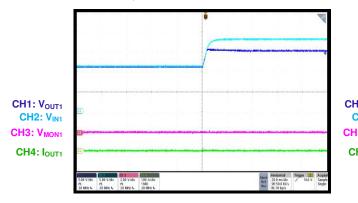


 $V_{IN1}$  = 12V,  $V_{IN2}$  = 5V,  $T_A$  = 25°C, unless otherwise noted.



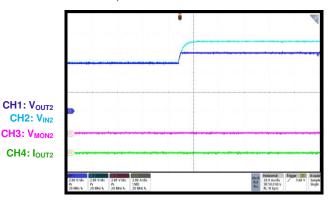
Output OVP

12V e-fuse, V<sub>IN1</sub> = 12V to 18V



Output OVP

5V e-fuse,  $V_{IN2} = 5V$  to 7V





# FUNCTIONAL BLOCK DIAGRAM

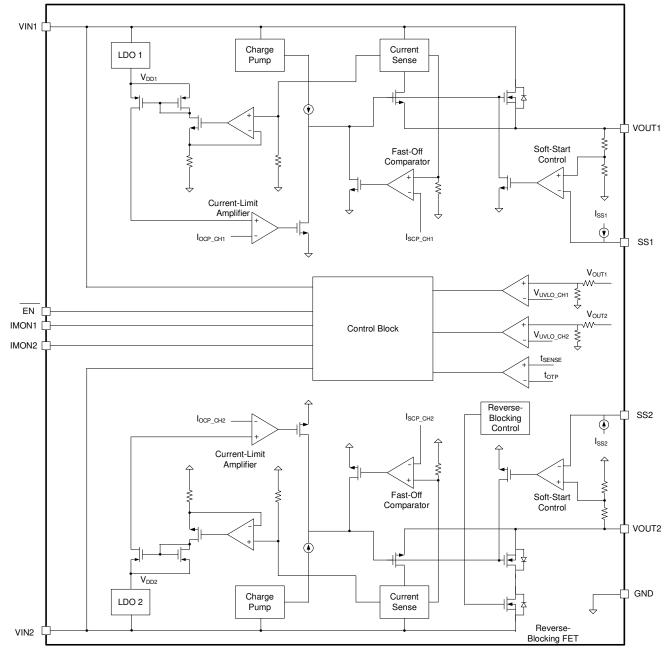


Figure 1: Functional Block Diagram



## OPERATION

The MP5098 is a 12V/5V, dual-channel e-fuse with current limiting. It is designed to limit the inrush current to the load while a circuit card is inserted into a live backplane power source. This limits the backplane's voltage drop and the dV/dt to the load. The MP5098 offers an integrated solution that can monitor the input voltage ( $V_{IN}$ ), output voltage ( $V_{OUT}$ ), output current ( $I_{OUT}$ ), and die temperature. This eliminates the need for an external current-sense resistor, power MOSFET, and thermal-sensing device.

#### Under-Voltage Lockout (UVLO) Protection

Channel 1 can be used in the 12V system, and channel 2 can be used in the 5V system. High energy transients can occur during normal operation or hot swap. These transients are determined by the wire's parasitic inductance and resistance, as well as the VCC capacitor ( $C_{VCC}$ ). If a power-clamped TVS diode is not used, then the e-fuse should be able to withstand the transient voltage. The MP5098 integrates a high-voltage MOSFET and a highvoltage circuit at VCC to guarantee safe operation.

If  $V_{IN}$  drops below the under-voltage lockout (UVLO) threshold, then the output is disabled. Once  $V_{IN}$  exceeds the UVLO threshold, the output is enabled.

#### Soft Start (SS)

Connect a capacitor to the SS pin to set the soft-start time ( $t_{SS}$ ).  $t_{SS}$  is a function of the soft-start capacitor ( $C_{SS}$ ). A constant-current source charges  $C_{SS}$ , and the SS voltage ( $V_{SS}$ ) ramps up.  $V_{OUT}$  ramps up at a similar slew rate to  $V_{SS}$ .

tss can be calculated with Equation (1):

$$t_{DV/DT}(ms) = \frac{1V \times C_{SS}(nF)}{I_{SS}}$$
(1)

Where  $t_{\text{DV/DT}}$  is  $t_{\text{SS}}$  between 0% and 100% of  $V_{\text{OUT}}$ , and  $I_{\text{SS}}$  is the soft-start current.

#### **Output Over-Voltage Protection (OVP)**

The MP5098 provides output over-voltage protection (OVP) to protect the downstream load from surge voltages at the input. An accurate, fast comparator monitors  $V_{\text{OUT}}$ . If  $V_{\text{OUT}}$ 

exceeds the OVP threshold, then the gate voltage ( $V_{GATE}$ ) of the internal MOSFETs is pulled down.  $V_{GATE}$  is regulated at a certain value to keep  $V_{OUT}$  clamped at the OVP threshold. Fast loop response speed (typically 2µs) reduces the over-voltage (OV) overshoot.

#### **Over-Current Protection (OCP)**

If an over-current (OC) fault occurs (e.g. the load exceeds the current limit  $[I_{\text{LIMIT_CHx}}]$  or a short occurs), then over-current protection (OCP) is triggered and the part enters constant-current mode. If the OC condition remains after 150µs, then the part enters hiccup mode and shuts down. After a 200ms off time (t<sub>OFF</sub>), the part starts up again. The MP5098 repeats this operation until the OC condition has been removed.

Channel 1's current limit ( $I_{\text{LIMIT}_CH1}$ ) is set at 4A internally, and its constant-current limit ( $I_{\text{LIMIT}_CC_CH1}$ ) is set at 2.5A. Channel 2's current limit ( $I_{\text{LIMIT}_CH2}$ ) is set at 3A internally, and its constant-current limit ( $I_{\text{LIMIT}_CC_CH2}$ ) is set at 1.3A.

#### Current Monitoring

The MP5098 provides current monitoring for both channel 1 and channel 2. The IMONx pin generates a current proportional to channel 1 and channel 2's load current ( $I_{LOAD_CHx}$ ). Connect a resistor to IMONx to generate the current monitor voltage ( $V_{IMONx}$ ). The effective  $V_{IMONx}$  range is between 0V and 2.5V to guarantee that the sensing results are linear.  $V_{IMONx}$  can be calculated with Equation (2):

 $V_{IMONx}(mV) = G_{IMONx} \times IOUT(A) \times R_{IMONx}(k\Omega)$ 

+  $I_{OSSFET_CHx} \times R_{IMONx}(k\Omega)$  (2)

Where  $G_{IMON\_CHx}$  is the current-sense gain,  $R_{IMON\_CHx}$  is the current-sense resistor, and  $I_{OFFSET CHx}$  is the current-sense offset.

#### Short Circuit Protection (SCP)

If the  $I_{LOAD\_CHx}$  increases rapidly due to a short circuit, the current may exceed  $I_{LIMIT\_CHx}$  before the control loop can respond. If the current reaches the secondary  $I_{LIMIT}$  level (8A), then short-circuit protection (SCP) is triggered and the fast turn-off circuit turn offs the MOSFET (see Figure 1 on page 15). This limits the peak current through the MOSFET to maintain  $V_{IN}$ . The total short-circuit response time is less than



1 $\mu$ s. Once the e-fuse turns off, the part starts up after a delay (200ms). If the short still remains, then V<sub>GATE</sub> is regulated to maintain the current at its I<sub>LIMIIT</sub> level, and the part enters hiccup mode after a 200ms off time (toFF). The MP5098 repeats this operation until the short circuit has been removed.

#### Enable

 $\overline{\text{EN}}$  is a digital control pin that enables and disabled the current-limit MOSFET. Pull  $\overline{\text{EN}}$  low

or float  $\overline{EN}$  to turn the current-limit MOSFET on; pull  $\overline{EN}$  high to turn it off. An internal 770k $\Omega$ resistor connected between  $\overline{EN}$  and GND allows  $\overline{EN}$  to float to start up the device.

#### **Thermal Shutdown**

Thermal shutdown monitors the silicon die temperature to prevent the chip from operating at exceedingly high temperatures. If the temperature exceeds 155°C, then the part shuts down.



## **APPLICATION INFORMATION**

#### Setting the Soft-Start Time (tss)

The soft-start time  $(t_{SS})$  is a function of the soft-start capacitor  $(C_{SS})$ .  $t_{SS}$  can be calculated with Equation (3):

$$t_{\text{DV/DT}}(\text{ms}) = \frac{1 \text{V} \times \text{C}_{\text{SS}}(\text{nF})}{\text{I}_{\text{SS}}}$$
(3)

Where  $t_{DV/DT}$  is  $t_{SS}$  between 0% and 100% of  $V_{OUT}$ .

#### **Design Example**

Table 1 shows a design example following the application guidelines for the specifications.

Table 1: Design Example

| V <sub>IN1</sub>  | 12V |
|-------------------|-----|
| V <sub>OUT1</sub> | 12V |
| V <sub>IN2</sub>  | 5V  |
| V <sub>OUT2</sub> | 5V  |

Figure 3 on page 19 shows the detailed application schematic. The typical performance and waveforms are shown in the Typical Characteristics section on page 7 and the Typical Performance Characteristics section on page 10. For more device applications, refer to the related evaluation board datasheet.

#### **PCB Layout Guidelines**

Efficient PCB layout is critical for stable operation. For best results, refer to Figure 2 and follow the guidelines below:

- 1. Place the high-current paths (VIN and VOUT) close to the device using short, direct, and wide traces.
- 2. Place the input capacitors as close to the VIN and GND pins as possible.
- 3. To improve thermal performance, connect the VIN pad to the large VIN plane, and the VOUT pad to the large VOUT plane.
- 4. Place C<sub>SS</sub> as close to SS pin as possible.

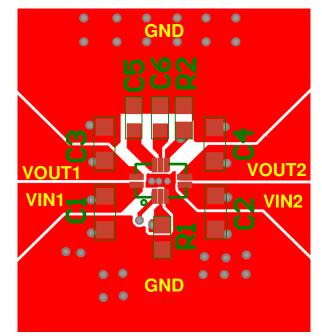
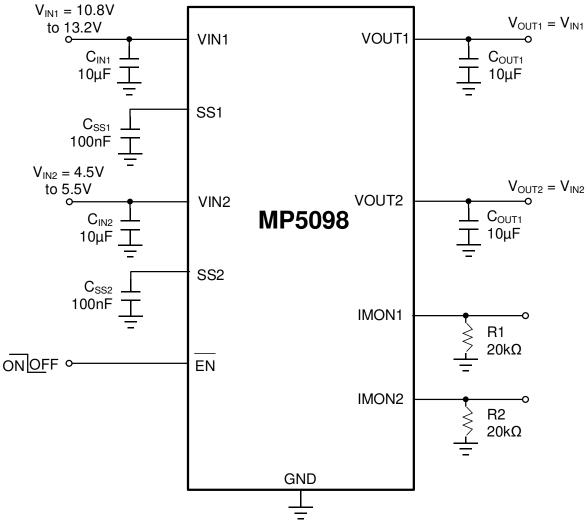


Figure 2: Recommended PCB Layout



# **TYPICAL APPLICATION CIRCUIT**

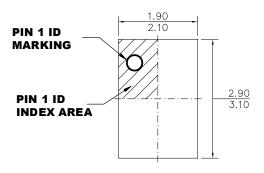


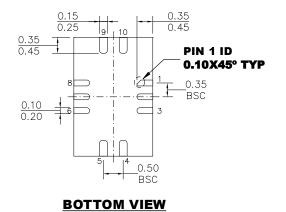
**Figure 3: Typical Application Circuit** 



# **PACKAGE INFORMATION**

TQFN-10 (2mmx3mm)

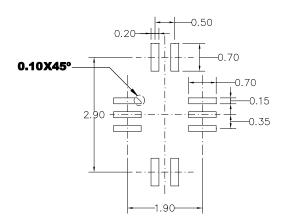




TOP VIEW



SIDE VIEW



#### **RECOMMENDED LAND PATTERN**

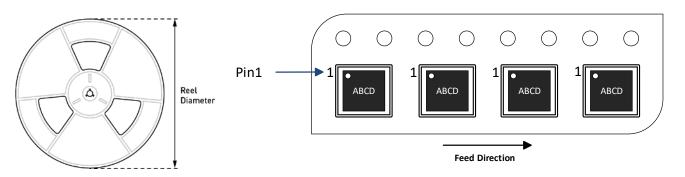
#### NOTE:

1) ALL DIMENSIONS ARE IN MILLIMETERS. 2) LEAD COPLANARITIES SHALL BE 0.08 MILLIMETERS MAX. 3) JEDEC REFERENCE IS MO-220.

4) DRAWING IS NOT TO SCALE.



# **CARRIER INFORMATION**



| Part Number | Package              | Quantity/ | Quantity/ | Quantity/ | Reel     | Carrier    | Carrier    |
|-------------|----------------------|-----------|-----------|-----------|----------|------------|------------|
|             | Description          | Reel      | Tube      | Tray      | Diameter | Tape Width | Tape Pitch |
| MP5098GDT-Z | TQFN-10<br>(2mmx3mm) | 5000      | N/A       | N/A       | 13in     | 12mm       | 8mm        |



## **REVISION HISTORY**

| Revision # | <b>Revision Date</b> | Description     | Pages Updated |  |  |
|------------|----------------------|-----------------|---------------|--|--|
| 1.0        | 11/02/2021           | Initial Release | -             |  |  |

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